Switching Transistor

PNP Silicon

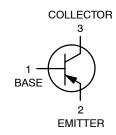
Features

- Moisture Sensitivity Level: 1
- ESD Rating: Human Body Model; 4 kV, Machine Model; 400 V
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant



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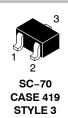
MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V _{CEO}	-40	Vdc
Collector-Base Voltage	V _{CBO}	-40	Vdc
Emitter-Base Voltage	V _{EBO}	-5.0	Vdc
Collector Current – Continuous	Ι _C	-600	mAdc

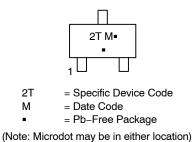
THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board T _A = 25°C	P _D	150	mW
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	833	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



MARKING DIAGRAM



*Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]
MMBT4403WT1G	SC–70 (Pb–Free)	3000 / Tape & Reel

+ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector-Emitter Breakdown Voltage (Note 1) ($I_C = -1.0$ mAdc, $I_B = 0$)	V _{(BR)CEO}	-40	-	Vdc
Collector-Base Breakdown Voltage ($I_C = -0.1 \text{ mAdc}, I_E = 0$)	V _{(BR)CBO}	-40	-	Vdc
Emitter-Base Breakdown Voltage ($I_E = -0.1 \text{ mAdc}, I_C = 0$)	V _{(BR)EBO}	-5.0	-	Vdc
Base Cutoff Current ($V_{CE} = -35$ Vdc, $V_{EB} = -0.4$ Vdc)	I _{BEV}	-	-0.1	μAdc
Collector Cutoff Current (V _{CE} = -35 Vdc, V _{EB} = -0.4 Vdc)	I _{CEX}	-	-0.1	μAdc

ON CHARACTERISTICS

$ \begin{array}{l} \text{DC Current Gain} \\ (I_{C} = -0.1 \text{ mAdc}, V_{CE} = -1.0 \text{ Vdc}) \\ (I_{C} = -1.0 \text{ mAdc}, V_{CE} = -1.0 \text{ Vdc}) \\ (I_{C} = -10 \text{ mAdc}, V_{CE} = -1.0 \text{ Vdc}) \\ (I_{C} = -150 \text{ mAdc}, V_{CE} = -2.0 \text{ Vdc}) \text{ (Note 1)} \\ (I_{C} = -500 \text{ mAdc}, V_{CE} = -2.0 \text{ Vdc}) \text{ (Note 1)} \end{array} $	h _{FE}	30 60 100 100 20	- - 300 -	-
Collector-Emitter Saturation Voltage (Note 1) ($I_C = -150 \text{ mAdc}, I_B = -15 \text{ mAdc}$) ($I_C = -500 \text{ mAdc}, I_B = -50 \text{ mAdc}$)	V _{CE(sat)}		-0.4 -0.75	Vdc
Base – Emitter Saturation Voltage (Note 1) ($I_C = -150 \text{ mAdc}, I_B = -15 \text{ mAdc}$) ($I_C = -500 \text{ mAdc}, I_B = -50 \text{ mAdc}$)	V _{BE(sat)}	-0.75 -	-0.95 -1.3	Vdc

SMALL-SIGNAL CHARACTERISTICS

Current-Gain – Bandwidth Product (I_C = –20 mAdc, V_{CE} = –10 Vdc, f = 100 MHz)	f _T	200	-	MHz
Collector-Base Capacitance (V_{CB} = -10 Vdc, I_E = 0, f = 1.0 MHz)	C _{cb}	-	8.5	pF
Emitter–Base Capacitance (V_{BE} = -0.5 Vdc, I_C = 0, f = 1.0 MHz)	C _{eb}	-	30	pF
Input Impedance (I _C = -1.0 mAdc, V _{CE} = -10 Vdc, f = 1.0 kHz)	h _{ie}	1.5	15	kΩ
Voltage Feedback Ratio ($I_C = -1.0 \text{ mAdc}$, $V_{CE} = -10 \text{ Vdc}$, f = 1.0 kHz)	h _{re}	0.1	8.0	X 10 ⁻⁴
Small-Signal Current Gain (I _C = -1.0 mAdc, V _{CE} = -10 Vdc, f = 1.0 kHz)	h _{fe}	60	500	-
Output Admittance ($I_C = -1.0 \text{ mAdc}$, $V_{CE} = -10 \text{ Vdc}$, f = 1.0 kHz)	h _{oe}	1.0	100	μmhos

SWITCHING CHARACTERISTICS

Delay Time	(V _{CC} = -30 Vdc, V _{FB} = -2.0 Vdc,	t _d	-	15	20
Rise Time	$I_{\rm C} = -150 \text{ mAdc}, I_{\rm B1} = -15 \text{ mAdc}$)	t _r	-	20	ns
Storage Time	$(V_{CC} = -30 \text{ Vdc}, I_C = -150 \text{ mAdc}, I_{B1} = I_{B2} = -15 \text{ mAdc})$	ts	-	225	20
Fall Time		t _f	-	30	ns

1. Pulse Test: Pulse Width \leq 300 $\mu s,$ Duty Cycle \leq 2.0%.

SWITCHING TIME EQUIVALENT TEST CIRCUIT

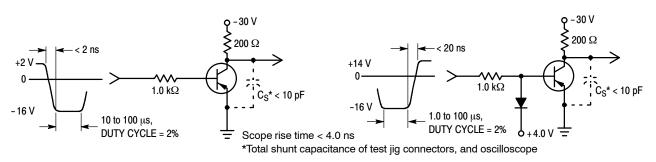
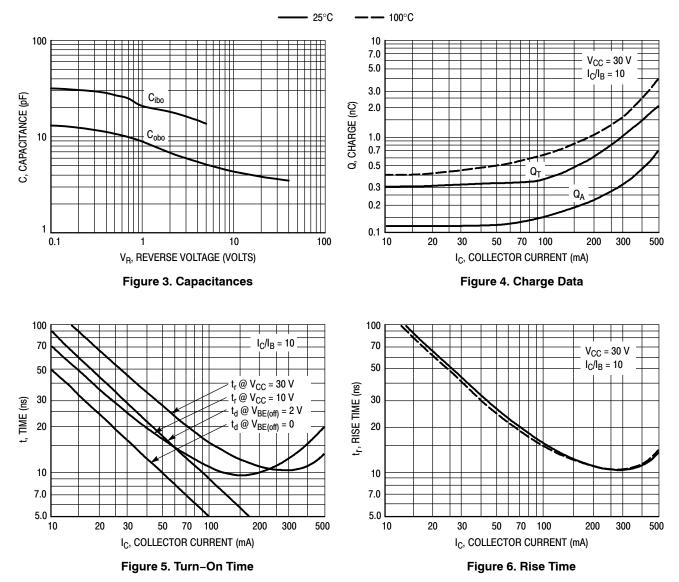


Figure 1. Turn-On Time

Figure 2. Turn-Off Time

TRANSIENT CHARACTERISTICS



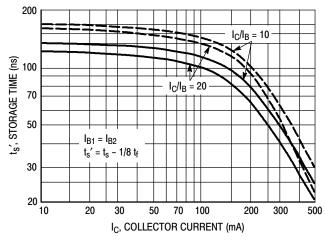
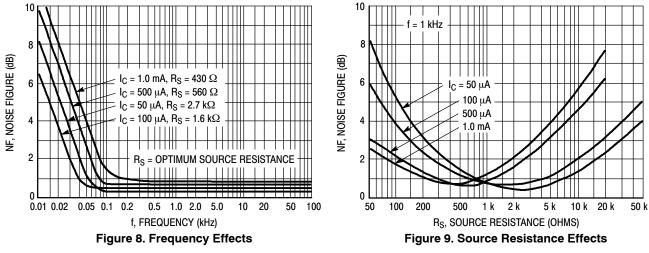


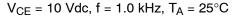
Figure 7. Storage Time

SMALL-SIGNAL CHARACTERISTICS NOISE FIGURE

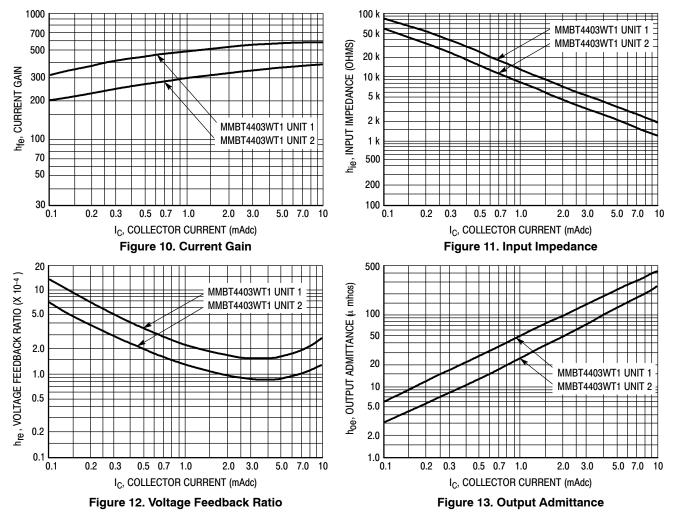
 $V_{CE} = -10$ Vdc, $T_A = 25^{\circ}C$; Bandwidth = 1.0 Hz

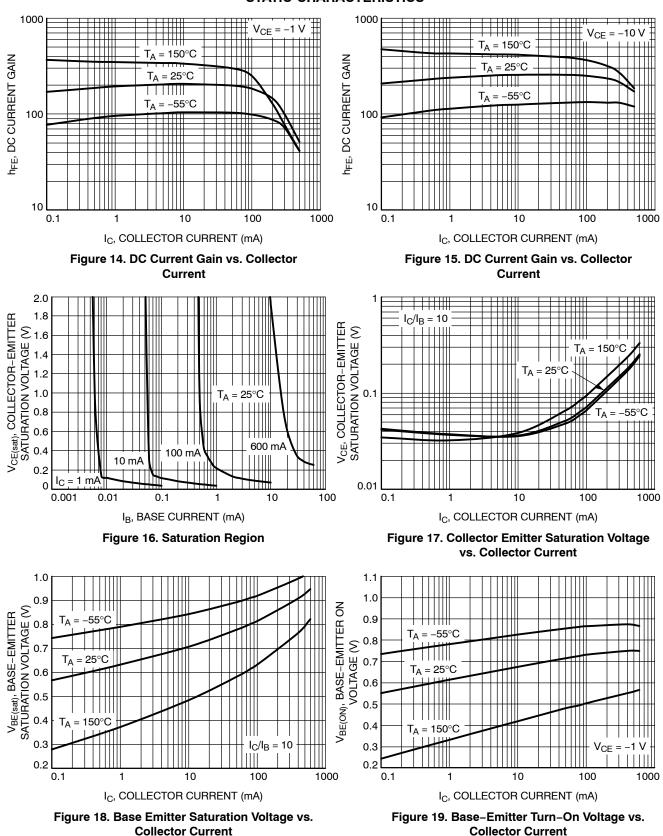


h PARAMETERS



This group of graphs illustrates the relationship between h_{fe} and other "h" parameters for this series of transistors. To obtain these curves, a high–gain and a low–gain unit were selected from the MMBT4403WT1 lines, and the same units were used to develop the correspondingly numbered curves on each graph.





STATIC CHARACTERISTICS

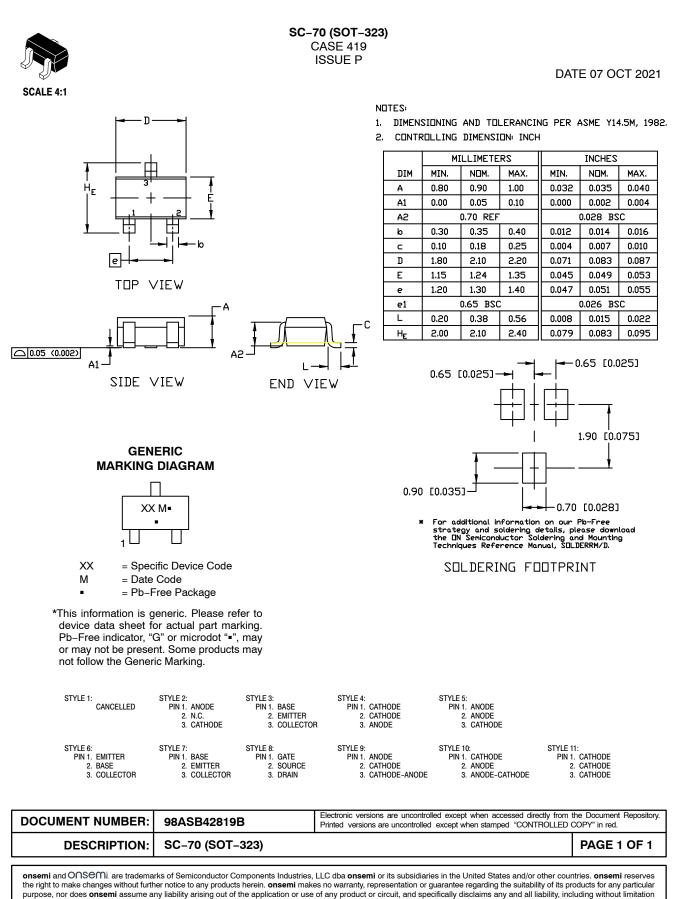
1000 0.5 0.0001 0.001 s 0 I_C, COLLECTOR CURRENT (mA) θ_{VC} for $\text{V}_{\text{CE(sat)}}$ 0.1 COEFFICIENT (mV/°C) 0.5 100 0.01 1.0 1.5 10 + θ_{VS} for V_{BE} 2.0 Single Pulse Test at T_A = 25°C 1 1 2.5 1 10 100 0.1 0.2 0.5 1.0 2.0 5.0 10 20 50 100 200 500 V_{CE}, COLLECTOR EMITTER VOLTAGE (V) I_C, COLLECTOR CURRENT (mA)

STATIC CHARACTERISTICS

Figure 20. Safe Operating Area

Figure 21. Temperature Coefficients

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